Product Specification 1000.750801 Issue Date 18 April 2024 17:37:3

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Part Number	Customer	
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Icemos Technology Ltd

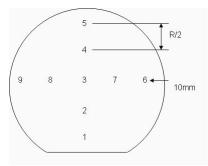
Category		Parameter	Specification	Measurement Method
OverallWafer	1.0	Diameter	150.00 +/- 0.20 mm	
	2.0	Primary Flat Orientation	{110} +/- 0.5 degree	Wafer Vendor
	3.0	Primary Flat Length	57.50 +/- 2.50 mm	Wafer Vendor
	4.0	Secondary Flat Orientation	none	Wafer Vendor
	5.0	Overall Thickness	408.00 +/- 6.00 μm	ADE, 100%
	6.0	Total Thickness Variation (TTV)	<3.00μm	Guaranteed by Process
	7.0	Bow	<60.00μm	ADE to ASTM F534, 100%
	8.0	Warp	<60.00μm	ADE to ASTM F534, 100%
	9.0	Edge Chips	0	Bright Light, 100%
	10.0	Edge Exclusion	5mm	
	11.0	Bond Process	Fusion Bonding	Guaranteed by Process
HandleSilicon	12.0	Handle Growth Method	CZ	Wafer Vendor
	13.0	Handle Orientation	{100} +/- 0.5 degree	Wafer Vendor
	14.0	Handle Thickness	400.00 +/- 5.00 μm	ADE, 100%
	15.0	Handle Doping Type	P	Wafer Vendor
	16.0	Handle Dopant	Boron	Wafer Vendor
	17.0	Handle Resistivity	1~20 Ohmem	Wafer Vendor
	18.0	Backside Finish	Polished with oxide, lasermark, and light handling marks	Guaranteed by process
BuriedOxide	19.0	Oxide Type	Thermal	
	20.0	Oxide Thickness	5,000.00 +/- 250.00 A	Nanospec centre point, 4%
	21.0	Oxide formed on	Handle or/and Device	
DeviceSilicon	22.0	Device Growth Method	CZ	Wafer Vendor
	23.0	Device Orientation	{100} +/- 0.5 degree	Wafer Vendor
	24.0	Nominal Thickness	7.50 +/- 0.50 μm	Filmetrics 9pts, 100% (note3)
	25.0	Distance to device silicon edge from wafer edge	< 2mm	Typical by Process
	26.0	Device Doping Type	N	Wafer Vendor
	27.0	Device Dopant	Phosphorous	Wafer Vendor
	28.0	Device Resistivity	0.4~1.15 Ohmem	Wafer Vendor
	29.0	Surface Voids	None	Bright Light, 100% (note2)
	30.0	Haze	None	Bright Light, 100% (note2)
	31.0	Scratches	none on the front-side	Bright Light, 100% (note2)

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Part Number		Customer				
Category	Parameter	Specification		Measurement Method		
Shipping Details	Wafer per box :	Max 25				
	Packaging:	Taped Polypropylene Wafer Box Empak, Ultrapak, 150.00mm Antistatic Double Bagging				
	Lot Shipment Data	Device Thickness Bow / Warp Data Handle and SOI Thickness				
Explanatory Notes	1. Microscope inspec	tion performed using microscope scan	as below. 5x object	ive.		
	2. All bright light ins	2. All bright light inspections performed exclude all wafer area outside the edge exclusion defined in Overall				

2. All bright light inspections performed exclude all water area outside the edge exclusion defined in Overal Wafer, Edge Exclusion. High intensity bright lamp inspection as per ASTM F523.

3. 9 point measurement are as shown in the diagram below:



Additional Information